

# **KSC945GBU Datasheet**



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DiGi Electronics Part Number KSC945GBU-DG

Manufacturer onsemi

Manufacturer Product Number KSC945GBU

Description TRANS NPN 50V 0.15A T092-3

Detailed Description Bipolar (BJT) Transistor NPN 50 V 150 mA 300MHz 2

50 mW Through Hole TO-92-3



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KSC945

# **Purchase and inquiry**

Manufacturer:
onsemi
Product Status:
Obsolete
Current - Collector (Ic) (Max):
150 mA
Vce Saturation (Max) @ lb, lc:
300mV @ 10mA, 100mA
DC Current Gain (hFE) (Min) @ Ic, Vce:
200 @ 1mA, 6V
Frequency - Transition:
300MHz
Mounting Type:
Through Hole
Supplier Device Package:
TO-92-3

# **Environmental & Export classification**

Moisture Sensitivity Level (MSL):	REACH Status:
1 (Unlimited)	REACH Unaffected
ECCN:	HTSUS:
FΔRQQ	8541 21 0075



# NPN Epitaxial Silicon Transistor

# **KSC945**

#### **Features**

- Audio Frequency Amplifier and High-Frequency OSC
- Complimentary to KSA733
- Collector-Base Voltage: V<sub>CBO</sub> = 60 V
- High Current Gain Bandwidth Product: f<sub>T</sub> = 300 MHz (Typical)
- Suffix "-C" Means Center Collector (1. Emitter 2. Collector 3. Base)

#### **ABSOLUTE MAXIMUM RATINGS**

(T<sub>A</sub> = 25°C unless otherwise noted.)

Symbol	Parameter	Ratings	Unit
V <sub>CBO</sub>	Collector-Base Voltage	60	V
V <sub>CEO</sub>	Collector-Emitter Voltage	50	V
V <sub>EBO</sub>	Emitter-Base Voltage	5	V
I <sub>C</sub>	Collector Current	150	mA
$T_J$	Junction Temperature	150	°C
T <sub>STG</sub>	Storage Temperature	-55 to 150	°C

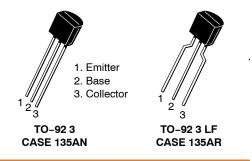
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

## THERMAL CHARACTERISTICS

 $(T_A = 25^{\circ}C \text{ unless otherwise noted.})$ 

Symbol	Parameter	Value	Unit
P <sub>D</sub>	Power Dissipation	250	mW
	Derate Above 25°C	2.0	mW/°C
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient	500	°C/W

2. PCB size: FR-4, 76 mm x 114 mm x 1.57 mm (3.0 inch x 4.5 inch x 0.062 inch) with minimum land pattern size.



### **MARKING DIAGRAM**



A = Assembly Site
C945Y = Specific Device Code
Y = Year of Production
WW = Work Week

#### **ORDERING INFORMATION**

Device	Package	Shipping
KSC945CYTA	TO-92 3 LF (Pb-Free)	2,000 Units / FNFLD
KSC945YTA	TO-92 3 LF (Pb-Free)	2,000 Units / FNFLD

# **DISCONTINUED** (Note 1)

KSC945YBU	TO-923	10,000 Units /
	(Pb-Free)	Bulk

 DISCONTINUED: This device is not recommended for new design. Please contact your onsemi representative for information. The most current information on this device may be available on <a href="https://www.onsemi.com">www.onsemi.com</a>.

# **KSC945**

# **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25°C unless otherwise noted.)

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
BV <sub>CBO</sub>	Collector-Base Breakdown Voltage	$I_C = 100 \mu A, I_E = 0$	60	_	_	V
BV <sub>CEO</sub>	Collector-Emitter Breakdown Voltage	I <sub>C</sub> = 10 mA, I <sub>B</sub> = 0	50	_	_	V
BV <sub>EBO</sub>	Emitter-Base Breakdown Voltage	$I_E = 10 \mu A, I_C = 0$	5	_	-	V
I <sub>CBO</sub>	Collector Cut-Off Current	V <sub>CB</sub> = 40 V, I <sub>E</sub> = 0	-	_	0.1	μΑ
I <sub>EBO</sub>	Emitter Cut-Off Current	$V_{EB} = 3 \text{ V, } I_{C} = 0$	-	_	0.1	μΑ
h <sub>FE</sub>	DC Current Gain	V <sub>CE</sub> = 6 V, I <sub>C</sub> = 1.0 mA	120	_	240	
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 100 mA, I <sub>B</sub> = 10 mA	-	0.15	0.30	V
f <sub>T</sub>	Current Gain Bandwidth Product	V <sub>CE</sub> = 6 V, I <sub>C</sub> = 10 mA	-	300	-	MHz
C <sub>ob</sub>	Output Capacitance	V <sub>CB</sub> = 6 V, I <sub>E</sub> = 0, f = 1 MHz	-	2.5	-	pF
NF	Noise Figure	$V_{CE}$ = 6 V, $I_{C}$ = 0.5 mA, f = 1 kHz, $R_{S}$ = 500 $\Omega$	-	4.0	_	dB

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

### **KSC945**

### **TYPICAL CHARACTERISTICS**

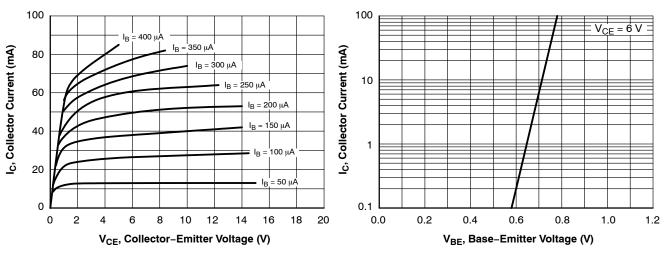


Figure 1. Static Characteristic

Figure 2. Transfer Characteristic

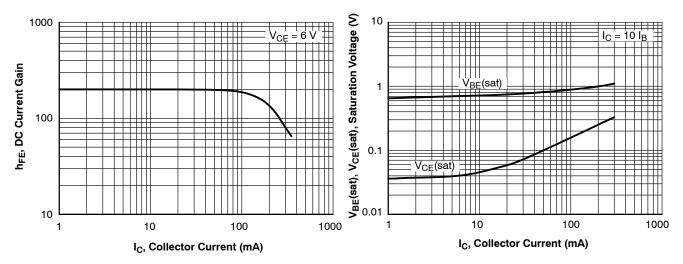


Figure 3. DC Current Gain

Figure 4. Base–Emitter Saturation Voltage and Collector–Emitter Saturation Voltage

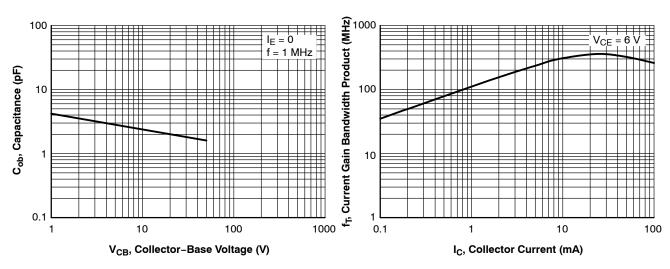


Figure 5. Output Capacitance

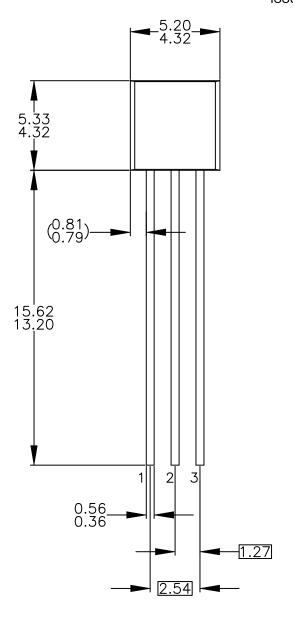
Figure 6. Current Gain Bandwidth Product

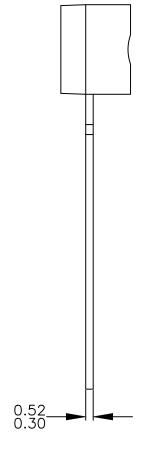


# MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS

## **TO-92 3 4.825x4.76** CASE 135AN ISSUE O

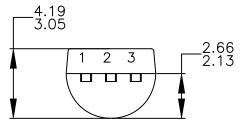
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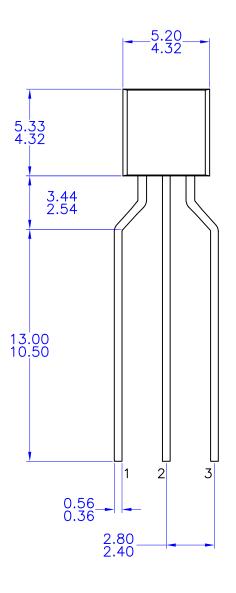
# MECHANICAL CASE OUTLINE

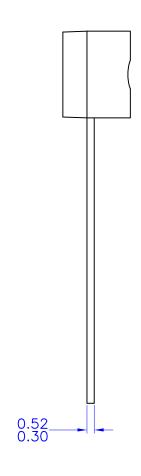
**PACKAGE DIMENSIONS** 

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CASE 135AR ISSUE O

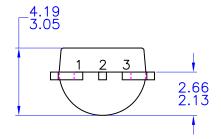
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